



ISO1176

SLLS897D-MARCH 2008-REVISED MARCH 2010

ISOLATED RS-485 PROFIBUS TRANSCEIVER

Check for Samples: ISO1176

FEATURES

www.ti.com

- 4000-V_{PEAK} Isolation, 560-V_{peak} V_{IORM}
 - UL 1577, IEC 60747-5-2 (VDE 0884, Rev. 2), IEC 61010-1, IEC 60950-1 and CSA Approved
- Bus-Pin ESD Protection
 - 16 kV HBM Between Bus Pins and GND2
 - 6 kV HBM Between Bus Pins and GND1
- Meets or Exceeds the Requirements of EN 50170 and TIA/EIA-485
- Signaling Rates up to 40 Mbps
- Differential Output Exceeds 2.1 V (54 Ω Load)

- Low Bus Capacitance 10 pF (MAX)
- 50 kV/µs Typical Transient Immunity
- Failsafe Receiver for Bus Open, Short, Idle
- 3.3-V Inputs are 5-V Tolerant

APPLICATIONS

- Profibus
- Factory Automation
- Networked Sensors
- Motor/Motion Control
- HVA and Building Automation Networks
- Networked Security Stations

DESCRIPTION

The ISO1176 is an isolated differential line transceiver designed for use in PROFIBUS applications. The device is ideal for long transmission lines since the ground loop is broken to provide for operation with a much larger common mode voltage range. The symmetrical isolation barrier of each device is tested to provide 2500 Vrms of isolation between the line transceiver and the logic level interface.

The galvanically isolated differential bus transceiver is an integrated circuit designed for bi-directional data communication on multipoint bus-transmission lines. The transceiver combines a galvanically isolated differential line driver and differential input line receiver. The driver has an active-high enable with isolated enable-state output on the ISODE pin (pin 10) to facilitate direction control. The driver differential outputs and the receiver differential inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus allowing up to 160 nodes.

The PV pin (pin 7) is provided as a full-chip enable option. All device outputs become high impedance when a logic low is applied to the PV pin. For more information, see the function tables in the device information section.

Any cabled I/O can be subjected to electrical noise transients from various sources. These noise transients can cause damage to the transceiver and/or near-by sensitive circuitry if they are of sufficient magnitude and duration. The ISO1176 can significantly reduce the risk of data corruption and damage to expensive control circuits.

The device is characterized for operation over the ambient temperature range of -40°C to 85°C.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

ISO1176

SLLS897D-MARCH 2008-REVISED MARCH 2010

TEXAS INSTRUMENTS

www.ti.com



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS

over operating junction temperature range unless otherwise noted⁽¹⁾

					VALUE	UNIT	
V _{CC1} , V _{CC2}	Supply voltag	e ⁽²⁾			-0.5 to 7	V	
Vo	Voltage at any	y bus I/O terminal			–9 to 14	V	
VI	Voltage input	at any D, DE or \overline{RE}		–0.5 to 7	V		
Io	Receiver outp	Receiver output current					
		Human Body Model		Bus pins to GND1	±6		
			JEDEC Standard 22, Test Method A114-C.01	Bus pins to GND2	±16		
ESD	Electrostatic	meder		All pins	±4	kV	
200	discharge	Charged Device Model	JEDEC Standard 22, Test Method C101	All pins	±1		
		Machine model	ANSI/ESDS5.2-1996	All pins	±200	V	
TJ	Maximum jun		170	°C			

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. All voltage values are with respect to the network ground terminal unless otherwise noted.

(2) All voltage values except differential I/O bus voltages are with respect to the referenced network ground terminal and are peak voltage values.

RECOMMENDED OPERATING CONDITIONS

			MIN	TYP MAX	UNIT	
V	Logic side supply voltage, V_{CC1} (with	respect to GND1)	3.15	5.5	V	
V _{CC}	Bus side supply voltage, V_{CC2} (with	respect to GND2)	4.75	5.25	v	
V_{CM}	Voltage at either bus I/O terminal	А, В	-7	12	V	
V		PV, RE	2	V _{CC1}	V	
VIH	High-level input voltage	D, DE	0.7 V _{CC1}		v	
V		PV, RE	0	0.8	V	
VIL	Low-level input voltage	D, DE		0.3 V _{CC1}	V	
V_{ID}	Differential input voltage	A with respect to B	-12	12	V	
	Output ourset	Driver	-70	70	A	
I _O	Output current	Receiver	-8	8	mA	
	Input pulse width		10		ns	
TJ	Operating junction temperature		-40	150	°C	

SUPPLY CURRENT

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
			DE at 0 V		4	6	
		3 V	DE at V _{CC1} , 2 Mbps		5		mA
	Logic side RMS supply current		DE at V _{CC1} , 25 Mbps		6		
ICC1	Logic side Rivis supply current		DE at 0 V		7	10	
		5.5 V	DE at V _{CC1} , 2 Mbps		8		mA
			DE at V _{CC1} , 25 Mbps		11		



SUPPLY CURRENT (continued)

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
			DE at 0 V		15	18	
I _{CC2}	Bus side RMS supply current	5.25 V	DE at V _{CC1} , 2 Mbps, 54 Ω load		70		mA
			DE at V _{CC1} , 25 Mbps, 54 Ω load		75		

ISODE-PIN ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OH} High-level out	High lovel output voltage	$I_{OH} = -8 \text{ mA}$	$V_{CC2} - 0.8$	4.6		V
	High-level output voltage	I _{OH} = -20 μA	$V_{CC2} - 0.1$	5		v
V		I _{OL} = 8 mA		0.2	0.4	V
V _{OL}	Low-level output voltage	I _{OL} = 20 μA		0	0.1	v

DRIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST (CONDITIONS	MIN	TYP	MAX	UNIT	
V _{OD}	Open-circuit differential output voltage	$ V_A - V_B $, Figure 7	1	1.5		V_{CC2}	V	
		See Figure 2 and	Figure 6	2.1				
V _{OD(SS)}	Steady-state differential output voltage magnitude	Common-mode lo V to 12 V, See Fig	ading with V _{test} from –7 gure 3	2.1			V	
$ \Delta V_{OD(SS)} $	Change in steady-state differential output voltage between logic states	$R_L = 54 \Omega$, See Fi	igure 4 andFigure 5	-0.2		0.2	V	
V _{OC(SS)}	Steady-state common-mode output voltage			2		3		
$\Delta V_{OC(SS)}$	Change in steady-state common-mode output voltage	$R_L = 54 \Omega$, See Figure 4 and Figure 5		-0.2		0.2	V	
V _{OC(PP)}	Peak-to-peak common-mode output voltage				0.5			
V _{OD(RING)}	Differential output voltage over and under shoot	See Figure 6 and Figure 10				10%	V _{OD(pp)}	
V _{I(HYS)}	Input voltage hysteresis	See Figure 7			150		mV	
	land to summer the	D, DE at 0 V or V	-10		10	٨		
II.	Input current	PV ⁽¹⁾ at 0 V or V _{CC1}				120	μA	
I _{O(OFF)}	Output current with power off	$V_{CC} \le 2.5 V$		See R	eceiver	input		
I _{OZ}	High impedance state output current	DE at 0 V		(current			
I _{OS(P)}	Peak short-circuit output current		$V_{OS} = -7$ V to 12 V	-250		250		
		DE at V _{CC} , See Figure 8 and	V _{OS} = 12 V, D at GND1			135	mA	
I _{OS(SS)}	Steady-state short-circuit output current	Figure 9	$V_{OS} = -7 V$, D at V_{CC1}	-135				
C _{OD}	Differential output capacitance			See F	Receiver	C _{IN}		
CMTI	Common-mode transient immunity	See Figure 20		25			kV/μs	

(1) The PV pin has a 50 k Ω pull-up resistor and leakage current depends on supply voltage.

SLLS897D - MARCH 2008 - REVISED MARCH 2010



www.ti.com

DRIVER SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{pLH} , t _{pHL}	Propagation delay time	V _{CC1} at 5 V				35	ns
t _{sk(p)}	Pulse skew (t _{p HL} - t _{pLH})	V _{CC2} at 5 V			2	5	ns
t _{pLH} , t _{pHL}	Propagation delay time	V _{CC1} at 3.3 V	at 3.3 V			40	ns
t _{sk(p)}	Pulse skew (t _{p HL} – t _{p LH})	V _{CC2} at 5 V	See Figure 10		2	5	ns
t _r	Differential output signal rise time			2	3	7.5	ns
t _f	Differential output signal fall time		2	3	7.5	ns	
t _{pDE}	DE to ISODE prop delay	See Figure 14			30	ns	
t _{t(MLH)} , t _{t(MHL)}	Output transition skew		See Figure 11			1	ns
$t_{p(AZH)}, t_{p(BZH)}$ $t_{p(AZL)}, t_{p(BZL)}$	Propagation delay time, high-impedance-to	-active output	_ C _L = 50 pF,			80	ns
$t_{p(AHZ)}, t_{p(BHZ)}$ $t_{p(ALZ)}, t_{p(BLZ)}$	Propagation delay time, active-to- high-imp	edance output	RE at 0 V, See Figure 12 and			80	ns
$\begin{array}{l} t_{p(AZL)} - t_{p(BZH)} \\ t_{p(AZH)} - t_{p(BZL)} \end{array}$	Enable skew time	Figure 13		0.55	1.5	ns	
t _(CFB)	Time from application of short-circuit to cur	rent foldback	See Figure 9		0.5		μs
t _(TSD)	Time from application of short-circuit to the	T _A = 25°C, See Figure 9	100			μs	

RECEIVER ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMET	ER	TEST	CONDITIONS	MIN	TYP	MAX	UNIT
V _{IT(+)}	Positive-going differential i	nput voltage threshold	SeeFigure 15	I _O = -8 mA		-80	-10	mV
V _{IT(-)}	Negative-going differential	input voltage threshold	I _O = 8 mA		-200	-120		mV
V _{hys}	s Hysteresis voltage (V _{IT+} – V _{IT-})					40		mV
V	High-level output voltage		V _{ID} = 200 mV,	$I_{OH} = -8 \text{ mA}$	V _{CC1} –0.4	3	v	V
V _{OH}	High-level output voltage	V_{CC1} at 3.3 V and V_{CC2} at	See Figure 15	$I_{O H} = -20 \ \mu A$	V _{CC1} -0.1	3.3		v
V	Low-level output voltage	5 V	$V_{ID} = -200 \text{ mV},$	I _{O L} = 8 mA		0.2	0.4	V
V _{OL}	Low-level output voltage		See Figure 15	I _{OL} = 20 μA		0	0.1	v
V	V _{OH} High-level output voltage		V _{ID} = 200 mV,	$I_{OH} = -8 \text{ mA}$	V _{CC1} –0.8	4.6		V
V _{OH}	High-level output voltage	V_{CC1} at 5 V and V_{CC2} at 5	See Figure 15	$I_{O H} = -20 \ \mu A$	V _{CC1} –0.1	5		v
V	V	$V_{ID} = -200 \text{ mV},$	I _{O L} = 8 mA		0.2	0.4	V	
V _{OL}	Low-level output voltage		See Figure 15	I _{OL} = -20 μA		0	0.1	v
I _A , I _B			$\lambda = 7 \lambda + 12 \lambda$	$V_{\rm CC}$ = 4.75 V or 5.25 V				
I _{A(OFF)} I _{B(OFF)}	Bus pin input current		$V_1 = -7 V \text{ or } 12 V,$ Other input = 0 V	V _{CC2} = 0 V	-160		200	μA
I _I	Receiver enable input curr	rent	RE = 0 V		-50		50	μA
I _{oz}	High-impedance state out	out current	$\overline{\text{RE}} = V_{\text{CC1}}$		-1		1	μA
R _{ID}	Differential input resistanc	e	А, В		48			kΩ
C _{ID}	Differential input capacitar	nce	Test input signal is a 1 V_{pp} amplitude , C_D A and B	1.5 MHz sine wave with is measured across		7	10	pF
C _{MR}	Common mode rejection		See Figure 19			4		V



ISO1176 SLLS897D – MARCH 2008 – REVISED MARCH 2010

www.ti.com

RECEIVER SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT	
t _{pLH} , t _{pHL}	Propagation delay time				50	20	
t _{sk(p)}	Pulse skew (t _{p HL} – t _{pLH})	- V _{CC1} at 5 V, V _{CC2} at 5 V		2	5	ns	
t _{pLH} , t _{pHL}	Propagation delay time		See Figure 16		55	5	
t _{sk(p)}	Pulse skew (t _{p HL} – t _{p LH})	- V _{CC1} at 3.3 V, V _{CC2} at 5 V	See Figure 16	2	5	ns	
t _r	Output signal rise time		2	4			
t _f	Output signal fall time			2	4	ns	
t _{pZH}	Propagation delay time, high-im	pedance-to-high-level output	DE at V _{CC1} ,	13	25		
t _{pHZ}	Propagation delay time, high-lev	See Figure 17	13	25	ns		
t _{pZL}	Propagation delay time, high-im	DE at V _{CC} ,	13	25	20		
t _{pLZ}	Propagation delay time, low-leve	el-to-high-impedance output	See Figure 18	13	25	ns	

PARAMETER MEASUREMENT INFORMATION



Figure 1. Open Circuit Voltage Test Circuit



Figure 2. V_{OD} Test Circuit



PARAMETER MEASUREMENT INFORMATION (continued)







Figure 4. Driver V_{OD} and V_{OC} Without Common-Mode Loading Test Circuit















Figure 7. Input Voltage Hysteresis Test Circuit



Figure 8. Driver Short-Circuit Test Circuit and Waveforms (Short Circuit applied at Time t=0)

Texas Instruments

www.ti.com

PARAMETER MEASUREMENT INFORMATION (continued)



















PARAMETER MEASUREMENT INFORMATION (continued)























Figure 17. Receiver Enable Test Circuit and Waveforms, Data Output High



Figure 18. Receiver Enable Test Circuit and Waveforms, Data Output Low



Figure 19. Common-Mode Rejection Test Circuit







Figure 20. Common-Mode Transient Immunity Test Circuit











TEXAS INSTRUMENTS

www.ti.com

DEVICE INFORMATION

DW PACKAGE (TOP VIEW)								
V _{CC1}	1 •	16	Ь	V _{CC2}				
GND 1 🔟	2	15	Ш	GND 2				
R	3	14	Ь	NC				
RE 🛙	4	13	Ш	В				
DE 🛙	5	12	Ь	А				
D	6	11	Ь	NC				
PV	7	10	Ь	ISODE				
GND 1 🔟	8	9	Ш	GND 2				

PACKAGE PIN FUNCTION DESCRIPTION

NAME	PIN NO.	FUNCTION
Vcc1	1	logic side power supply
GND1	2, 8	logic side ground, internally connected
R	3	receiver output
RE	4	receiver logic-low enable
DE	5	driver logic-high enable input
D	6	driver input
PV	7	ISO1176 chip enable, logic high applied immediately after power-up for device operation. A logic low 3-states all outputs.
GND2	9, 15	bus side ground, internally connected
ISODE	10	bus-side driver enable output
nc	11, 14	not connected internally, may be left floating
А	12	non-inverting bus output
В	13	inverting bus output
Vcc2	16	bus side power supply



DRIVER FUNCTION TABLE

V _{CC1}	V _{CC2}	POWER	INPUT	ENABLE	ENABLE	OUTI	PUTS
		VALID (PV) (ISO1176)	(D)	INPUT (DE)	OUTPUT (ISODE)	Α	В
PU	PU	H or open	Н	Н	Н	Н	L
PU	PU	H or open	L	Н	Н	L	Н
PU	PU	H or open	Х	L	L	Z	Z
PU	PU	H or open	Х	open	L	Z	Z
PU	PU	H or open	open	н	Н	н	L
PD	PU	Х	Х	Х	L	Z	Z
PU	PD	Х	Х	Х	L	Z	Z
PD	PD	Х	Х	Х	L	Z	Z
Х	Х	L	Х	Х	L	Z	Z
H = high lev	el, L= low leve	el, X = don't ca	are, Z = high i	mpedance (of	ff), ? = indetermina	te	

RECEIVER FUNCTION TABLE

V _{CC1}	V _{CC2}	POWER VALID (PV) (ISO1176)	DIFFERENTIAL INPUT V _{ID} = (V _A – V _B)	ENABLE (RE)	OUTPUT ®)
PU	PU	H or open	-0.01 V ≤ V _{ID}	L	Н
PU	PU	H or open	-0.2 V < V _{ID} < -0.01 V	L	?
PU	PU	H or open	V _{ID} ≤ -0.2 V	L	L
PU	PU	H or open	Х	Н	Z
PU	PU	H or open	יס X סו		Z
PU	PU	H or open	Open circuit	L	Н
PU	PU	H or open	Short Circuit	L	Н
PU	PU	H or open	Idle (terminated) bus	L	Н
PD	PU	Х	Х	Х	Z
PU	PD	H or open	Х	L	Н
PD	PD	Х	Х	Х	Z
Х	Х	L	Х	Х	Z

H = high level, L= low level, X = don't care, Z = high impedance (off), ? = indeterminate



EQUIVALENT CIRCUIT SCHEMATICS







IEC SAFETY LIMITING VALUES

Safety limiting intends to prevent potential damage to the isolation barrier upon failure of input or output circuitry. A Failure of the IO can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier potentially leading to secondary system failures.

	PARAMETER	TEST CONDITIONS			TYP	MAX	UNIT
I _S	Safety input, output, or supply current	DW-16	$\theta_{JA} = 212^{\circ}$ C/W, V _I = 5.5 V, T _J = 170°C, T _A = 25°C			128	mA
T_S	Maximum case temperature	DW-16				150	°C

The safety-limiting constraint is the absolute maximum junction temperature specified in the absolute maximum ratings table. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determines the junction temperature. The assumed junction-to-air thermal resistance in the Thermal Characteristics table is that of a device installed in the JESD51-3, Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages and is conservative. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.

SLLS897D-MARCH 2008-REVISED MARCH 2010

www.ti.com

THERMAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
θ_{JA}	lunation to air	Low-K thermal resistance ⁽¹⁾	168			00 AA
	Junction-to-air	High-K board ⁽¹⁾		96.1		°C/W
θ_{JB}	Junction-to-board thermal resistance			61		°C/W
θ_{JC}	Junction-to-case thermal resistance			48		°C/W
P _D	Device power dissipation	$V_{CC1} = V_{CC2} = 5.25 \text{ V}, \text{ T}_{J} = 150^{\circ}\text{C}, \text{ C}_{L} = 15 \text{ pF},$ Input a 20 MHz 50% duty cycle square wave			220	mW

(1) Tested in accordance with the Low-K or High-K thermal metric definitions of EIA/JESD51-3 for leaded surface mount packages.





PACKAGE CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
L(I01)	Minimum air gap (Clearance)	Shortest terminal to terminal distance through air	8.34			mm
L(102)	Minimum external tracking (Creepage) ⁽¹⁾	Shortest terminal to terminal distance across the package surface	8.1			mm
СТІ	Tracking resistance (Comparative Tracking Index)	DIN IEC 60112 / VDE 0303 Part 1	≥175			V
	Minimum Internal Gap (Internal Clearance)	Distance through the insulation	0.008			mm
R _{IO}	Isolation resistance	Input to output, V_{IO} = 500 V, all pins on each side of the barrier tied together creating a two-terminal device		>10 ¹²		Ω
CIO	Barrier capacitance Input to output	$V_{I} = 0.4 \sin (4E6\pi t)$		2		pF
CI	Input capacitance to ground	$V_1 = 0.4 \sin (4E6\pi t)$		2		pF

(1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed circuit board do not reduce this distance.

Creepage and clearance on a printed circuit board become equal according to the measurement techniques shown in the Isolation Glossary. Techniques such as inserting grooves and/or ribs on a printed circuit board are used to help increase these specifications.

REGULATORY INFORMATION

VDE	CSA	UL
Certified according to IEC 60747-5-2	Approved under CSA Component Acceptance Notice	Recognized under 1577 Component Recognition Program ⁽¹⁾
File Number: 40014131	File Number: 1698195	File Number: E181974

(1) Production tested \ge 3000 Vrms for 1 second in accordance with UL 1577.

IEC 60554-1 RATINGS TABLE

PARAMETER	TEST CONDITIONS	SPECIFICATION
Basic isolation group	Material group	Illa
	Rated mains voltage < 150 VRMS	I-IV
Installation classification	Rated mains voltage < 300 VRMS	1-111
	Rated mains voltage < 400 VRMS	I-II

IEC 60747-5-2 INSULATION CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	SPECIFICATION	UNIT
VIORM	Maximum working insulation voltage		560	V
V _{PR}	Input to output test voltage	Method b1, $V_{PR} = V_{IORM} \times 1.875$, 100% Production test with t = 1 s, Partial discharge <5 pC	1050	V
VIOTM	Transient overvoltage	t = 60 s	4000	V
R _S	Insulation resistance	$V_{IO} = 500 \text{ V at } T_{S}$	>10 ⁹	Ω
	Pollution degree		2	



APPLICATION INFORMATION

Transient Voltages

Isolating of a circuit insulates it from other circuits and earth, so that noise voltage develops across the insulation rather than circuit components. The most common noise threat to data-line circuits is voltage surges or electrical fast transients that occur after installation. The transient ratings of the ISO1176 standard are sufficient for all but the most severe installations. However, some equipment manufacturers use ESD generators to test equipment transient susceptibility. This practice can exceed insulation ratings. ESD generators simulate static discharges that may occur during device or equipment handling with low-energy but high-voltage transients.

Figure 29 models the ISO1176 bus IO connected to a noise generator. C_{IN} and R_{IN} is the device, and any other stray or added capacitance or resistance across the A or B pin to GND2. C_{ISO} and R_{ISO} is the capacitance and resistance between GND1 and GND2 of the ISO1176, plus those of any other insulation (transformer, etc.). Stray inductance is assumed to be negligible.

From this model, the voltage at the isolated bus return is

$$v_{GND2} = v_N \frac{Z_{ISO}}{Z_{ISO} + Z_{IN}}$$
(1)

and is always less than 16 V from $V_{\rm N}\!.$ If the ISO1176 is tested as a stand-alone device,

- $R_{IN} = 6 \times 10^4 \Omega$,
- C_{IN}= 16 x 10⁻¹² F,
- $R_{ISO} = 10^9 \Omega$ and
- C_{ISO}= 10⁻¹² F.

Notice from Figure 29 that the resistor ratio determines the voltage ratio at low frequencies, and that the inverse capacitance ratio determines the voltage ration at high frequencies. In the stand-alone case and for low frequencies,

$$\frac{v_{GND2}}{v_N} = \frac{R_{ISO}}{R_{ISO} + R_{IN}} = \frac{10^9}{10^9 + 6 \times 10^4}$$
(2)

or essentially all of the noise appears across the barrier.

At high frequencies,

$$\frac{v_{GND2}}{v_N} = \frac{\frac{1}{C_{ISO}}}{\frac{1}{C_{ISO}} + \frac{1}{C_{IN}}} = \frac{1}{1 + \frac{C_{ISO}}{C_{IN}}} = \frac{1}{1 + \frac{1}{16}} = 0.94$$
(3)

and 94% of $V_{\rm N}$ appears across the barrier. As long as $R_{\rm ISO}$ is greater than $R_{\rm IN}$ and $C_{\rm ISO}$ is less than $C_{\rm IN},$ most of the transient noise appears across the isolation barrier, as it should.

Using ESD generators to test equipment transient susceptibility, or considering product claims of ESD ratings above the barrier transient ratings of an isolated interface is not recommended. ESD is best managed through recessing or covering connector pins in a conductive connector shell, and by proper installer training.



Figure 29. Device Model For Static Discharge Testing



ISO1176 "Sticky Bit" Issue (Under Certain Conditions)

Summary: In applications with sufficient differential noise on the bus, the output of the ISO1176 receiver may "stick" at an incorrect state for up to $30 \ \mu s$.

Description: The ISO1176 isolated Profibus (RS-485) transceiver is rated for signaling up to 40 Mbps on twisted-pair bus lines. The receiver thresholds comply with RS-485 and Profibus specifications; an input differential voltage $V_{ID} = V_A - V_B > 200$ mV causes a logic High on the R output, and $V_{ID} < -200$ mV causes a logic Low on the R output. To assure a known receiver output when the bus is shorted or idle, the upper threshold is set below zero, such that $V_{ID} = 0$ mV causes a logic High on the R output. The data sheet specifies a typical upper threshold (V_{IT+}) of -80 mV and a typical lower threshold (V_{IT-}) of -120 mV.

At a signaling rate of 40 Mbps, each valid data bit has a duration of 25 ns. At typical Profibus signaling rates of 12 Mbps or lower, each valid data bit has a duration of 83 ns or more. The ISO1176 correctly sets the R output for each of these valid data bits.

In applications with a high degree of differential noise on the bus lines, it is possible to get short periods when an invalid bus voltage triggers a change in state of the internal receiver circuits. An issue with the digital isolation channel in the ISO1176 may cause the invalid receiver state to "stick" rather than immediately transition back to the correct state. The receiver output will always transition to the correct state, but may stick in the incorrect state for up to 30 µs. This can cause a temporary loss of data.





Changes from Revision A (May 2008) to Revision B

Changes from Original (March 2008) to Revision A

•	Changed L(IO1), Minimum air gap (Clearance) in the PACKAGE CHARACTERISTICS table From: MIN = 7.7mm	
	To: 8.34mm	

Changes from Revision B (June 2008) to Revision C

 Changed the text in the second paragraph of the DESCRIPTON From: whenever the driver is disabled or V_{CC2} = 0 To: allowing up to 160 nodes.

Changes from Revision C (October 2008) to Revision D

•	Added 560-Vpeak V _{IORM} to the first Features List	. 1
•	Added UL 1577, IEC 60747-5-2 (VDE 0884, Rev. 2), to the Features List	. 1
•	Added Input pulse width MIN = 10 ns to the RECOMMENDED OPERATING CONDITIONS table	. 2
•	Added the CSA column to the Regulatory Information table	19
•	Changed the ISO1176 "Sticky Bit" Issue section	21

Page

NSTRUMENTS

XAS

Page

Page

Page

24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish		Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
ISO1176DW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ISO1176	Samples
ISO1176DWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ISO1176	Samples
ISO1176DWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ISO1176	Samples
ISO1176DWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	ISO1176	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





24-Jan-2013

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Packago	Package	Die
*All dimensions are nominal			

	Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
1	ISO1176DWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ISO1176DWR	SOIC	DW	16	2000	367.0	367.0	38.0

DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AA.



LAND PATTERN DATA



NOTES:

A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications			
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive		
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications		
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers		
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps		
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy		
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial		
Interface	interface.ti.com	Medical	www.ti.com/medical		
Logic	logic.ti.com	Security	www.ti.com/security		
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense		
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video		
RFID	www.ti-rfid.com				
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com		
Wireless Connectivity	www.ti.com/wirelessconnectivity				

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный) **Факс:** 8 (812) 320-02-42 **Электронная почта:** <u>org@eplast1.ru</u> **Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.